

TOSHIBA TRANSISTOR SILICON PNP EPITAXIAL TYPE (PCT PROCESS)

2SA966

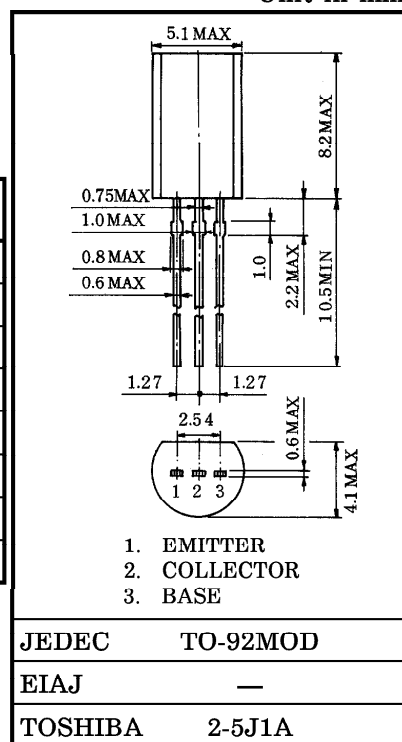
AUDIO POWER AMPLIFIER APPLICATIONS.

Unit in mm

- Complementary to 2SC2236 and 3Watts Output Applications.

MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CB0}	-30	V
Collector-Emitter Voltage	V_{CE0}	-30	V
Emitter-Base Voltage	V_{EB0}	-5	V
Collector Current	I_C	-1.5	A
Emitter Current	I_E	1.5	A
Collector Power Dissipation	P_C	900	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55~150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

Weight : 0.36g

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = -30\text{V}, I_E = 0$	—	—	-100	nA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -5\text{V}, I_C = 0$	—	—	-100	nA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -10\text{mA}, I_B = 0$	-30	—	—	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -1\text{mA}, I_C = 0$	-5	—	—	V
DC Current Gain	h_{FE} (Note)	$V_{CE} = -2\text{V}, I_C = -500\text{mA}$	100	—	320	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -1.5\text{A}, I_B = -0.03\text{A}$	—	—	-2.0	V
Base-Emitter Voltage	V_{BE}	$V_{CE} = -2\text{V}, I_C = -500\text{mA}$	—	—	-1.0	V
Transition Frequency	f_T	$V_{CE} = -2\text{V}, I_C = -500\text{mA}$	—	120	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10\text{V}, I_E = 0, f = 1\text{MHz}$	—	—	30	pF

Note : h_{FE} Classification O : 100~200, Y : 160~320

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